# International

#### $\mathsf{HEXFRED}^{^{\mathrm{TM}}}$

#### Features

- Ultrafast Recovery
- Ultrasoft Recovery
- Very Low I<sub>RRM</sub>
- Very Low Qrr
- · Specified at Operating Conditions

#### **Benefits**

- · Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count

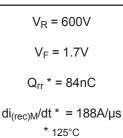
#### Description

International Rectifier's HFA15TB60 is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 8 amps per Leg continuous current, the HFA15TB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I<sub>RRM</sub>) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA15TB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

### HFA15TB60 HFA15TB60-1

#### Ultrafast, Soft Recovery Diode

Bulletin PD -2.334 rev. C 11/03







	Parameter	Мах	Units	
V <sub>R</sub>	Cathode-to-Anode Voltage	600	V	
I <sub>F</sub> @ T <sub>C</sub> = 100°C	Continuous Forward Current	15		
I <sub>FSM</sub>	Single Pulse Forward Current	150	A	
I <sub>FRM</sub>	Maximum Repetitive Forward Current	60	7	
P <sub>D</sub> @ T <sub>C</sub> = 25°C	Maximum Power Dissipation	74		
P <sub>D</sub> @ T <sub>C</sub> = 100°C	Maximum Power Dissipation	29	- w	
TJ	Operating Junction and	- 55 to +150		
T <sub>STG</sub>	Storage Temperature Range			

#### **Absolute Maximum Ratings**

Bulletin	PD-2.334	rev. C	11/03	

#### Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter	Min	Тур	Max	Units	Test Conditions	
V <sub>BR</sub>	Cathode Anode Breakdown Voltage	600			V	I <sub>R</sub> = 100μA	
V <sub>FM</sub>	Max Forward Voltage		1.3	1.7		I <sub>F</sub> = 15A	
			1.5	2.0	V	I <sub>F</sub> = 30A See Fig. 1	
			1.2	1.6		I <sub>F</sub> = 15A, T <sub>J</sub> = 125°C	
I <sub>RM</sub>	Max Reverse Leakage Current		1.0	10	μA	V <sub>R</sub> = V <sub>R</sub> Rated See Fig. 2	
IRM			400	1000	μΑ	$T_J$ = 125°C, $V_R$ = 0.8 x $V_R$ Rated	
CT	Junction Capacitance		25	50	pF	V <sub>R</sub> = 200V See Fig. 3	
L <sub>S</sub>	Corico Industance		8.0		nH	Measured lead to lead 5mm from	
	Series Inductance					package body	

#### Dynamic Recovery Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter	Min	Тур	Max	Units	Test Conditions	
t <sub>rr</sub>	Reverse Recovery Time		19			$I_F$ = 1.0A, di <sub>f</sub> /dt = 200A/µs, V <sub>R</sub> = 30V	
t <sub>rr1</sub>	See Fig. 5		42	60	ns	T <sub>J</sub> = 25°C	
t <sub>rr2</sub>	-		74	120		T <sub>J</sub> = 125°C	I <sub>F</sub> = 15A
I <sub>RRM1</sub>	Peak Recovery Current		4.0	6.0	А	T <sub>J</sub> = 25°C	
I <sub>RRM2</sub>	See Fig. 6		6.5	10	^	T <sub>J</sub> = 125°C	V <sub>R</sub> = 200V
Q <sub>rr1</sub>	Reverse Recovery Charge		84	180	nC	T <sub>J</sub> = 25°C	
Q <sub>rr2</sub>	See Fig. 7		241	600	no	T <sub>J</sub> = 125°C	di <sub>f</sub> /dt = 200A/µs
di <sub>(rec)M</sub> /dt1	Peak Rate of Fall of Recovery Current		188		A/µs	T <sub>J</sub> = 25°C	
di <sub>(rec)M</sub> /dt2	During t <sub>b</sub> See Fig. 8		160		Αγμs	T <sub>J</sub> = 125°C	

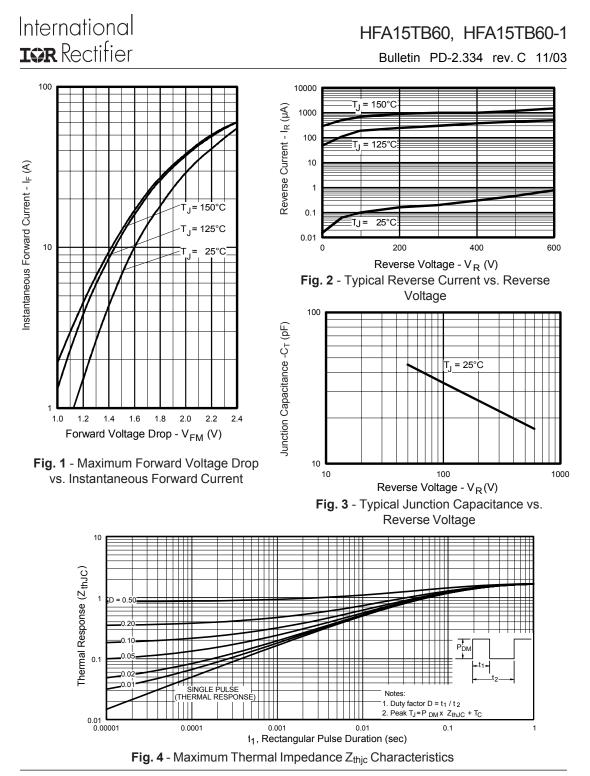
#### **Thermal - Mechanical Characteristics**

	Parameter	Min	Тур	Мах	Units
T <sub>lead</sub> ①	Lead Temperature			300	°C
R <sub>thJC</sub>	Thermal Resistance, Junction to Case			1.7	
R <sub>thJA</sub> ②	Thermal Resistance, Junction to Ambient			80	K/W
RthCS 3	Thermal Resistance, Case to Heat Sink		0.5		
Wt	Weight		2.0		g
	Weight		0.07		(oz)
т	Mounting Torque	6.0		12	Kg-cm
		5.0		10	lbf•in

① 0.063 in. from Case (1.6mm) for 10 sec

② Typical Socket Mount

3 Mounting Surface, Flat, Smooth and Greased



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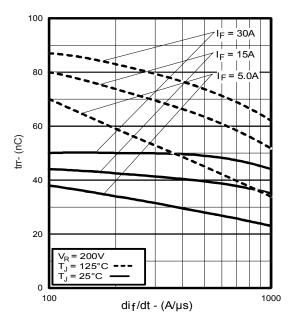


Fig. 5 - Typical Reverse Recovery vs. dif/dt

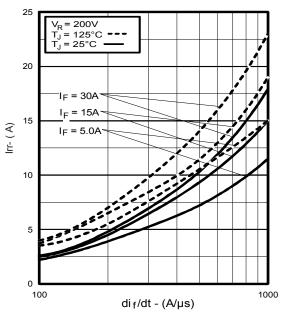
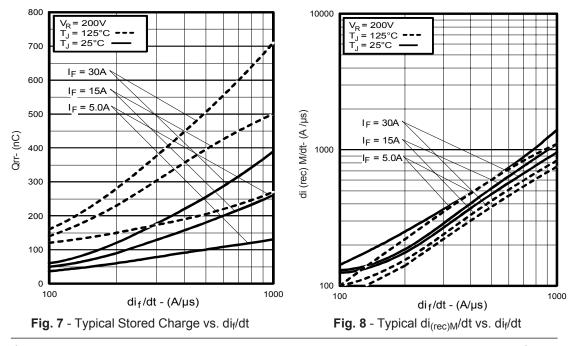


Fig. 6 - Typical Recovery Current vs. dif/dt

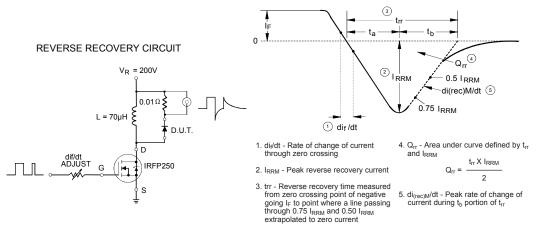


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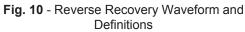
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10.54 (0.41) 1.32 (0.05) 3.78 (0.15) DIA. MAX. 1.22 (0.05) 3.54 (0.14) . \* 6.48 (0.25)  $\oplus$ 2.92 (0.11) 6.23 (0.24) 15.24 (0.60) 2.54 (0.10) 14.84 (0.58) TERM 2 피 Base Cathode 14.09 (0.55) 3.96 (0.16) Q 2 0.10 (0.004) 13.47 (0.53) 3.55 (0.14) 2.04 (0.080) MAX. 1.40 (0.05) 2.89 (0.11) 1.15 (0.04) 2.64 (0.10) 0.94 (0.04) 0.69 (0.03) Ó 1 **d** 3 Cathode Anode 0.61 (0.02) MAX. 4.57 (0.18) 4.32 (0.17) 5.08 (0.20) REF. Conforms to JEDEC Outline TO-220AC Dimensions in millimeters and inches

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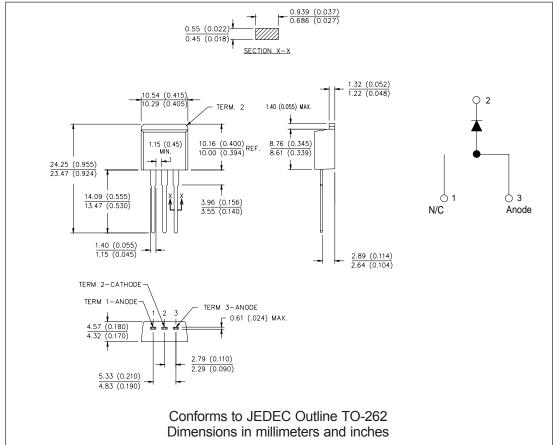
**Outline Table** 

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Bulletin PD-2.334 rev. C 11/03

#### **Outline Table**



Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level. Qualification Standards can be found on IR's Web site.

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